

# EVVOSEMI<sup>®</sup>

THINK CHANGE DO



ESD



TVS



MOS



LDO



Diode



Sensor



DC-DC

## Product Specification

▶ Domestic	Part Number	MB1F - MB10F
▶ Overseas	Part Number	MB1F - MB10F
▶ Equivalent	Part Number	MB1F - MB10F

EV is the abbreviation of name EVVO

## ■ 1A Surface Mount Glass Passivated Bridge Rectifier

### ■ Features

- Glass Passivated Chip Junction
- Reverse Voltage - 100 to 1000 V
- Forward Current - 1 A
- High Surge Current Capability
- Designed for Surface Mount Application



■ Simplified outline(MBF)

### Pinning

PIN	DESCRIPTION
1	Input Pin ( ~ )
2	Input Pin ( ~ )
3	Output Anode ( + )
4	Output Cathode ( - )

### ■ Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

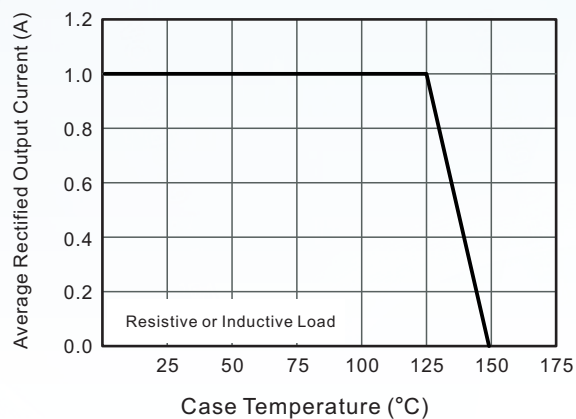
Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	MB1F	MB2F	MB4F	MB6F	MB8F	MB10F	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	100	200	400	600	800	1000	V
Average Rectified Output Current at $T_c = 125\text{ }^{\circ}\text{C}$	$I_O$	1.0						A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	$I_{FSM}$	35						A
Maximum Forward Voltage at 1.0 A	$V_F$	1.1						V
Maximum DC Reverse Current @ $T_A=25\text{ }^{\circ}\text{C}$ at Rated DC Blocking Voltage @ $T_A=125\text{ }^{\circ}\text{C}$	$I_R$	5 40						$\mu\text{A}$
Typical Junction Capacitance ( Note1 )	$C_j$	13						pF
Typical Thermal Resistance ( Note2 )	$R_{\theta JA}$ $R_{\theta JC}$	80 25						$^{\circ}\text{C/W}$
Operating and Storage Temperature Range	$T_j, T_{stg}$	-55 ~ +150						$^{\circ}\text{C}$

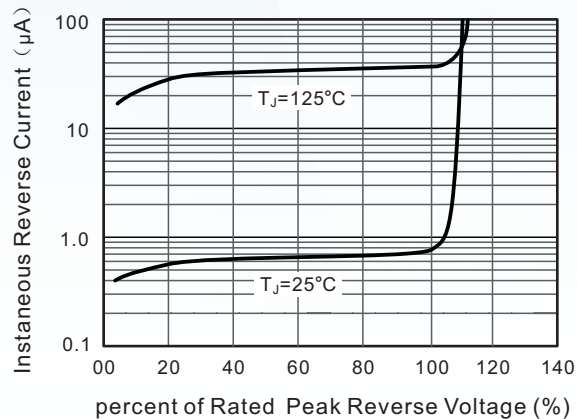
Note: 1. Measured at 1MHz and applied reverse voltage of 4 V D.C.

2. Mounted on glass epoxy PC board with 4×1.5"×1.5" ( 3.81×3.81 cm ) copper pad.

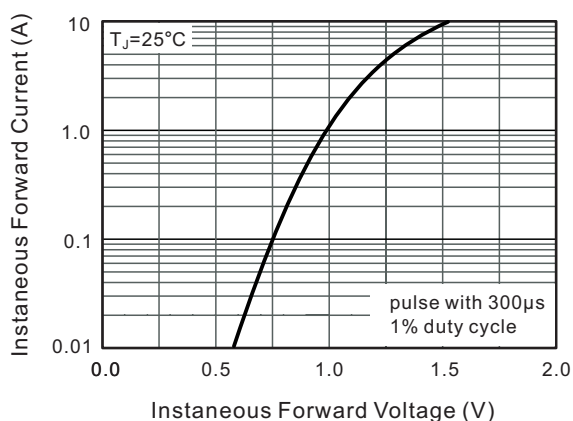
**Fig.1 Average Rectified Output Current Derating Curve**



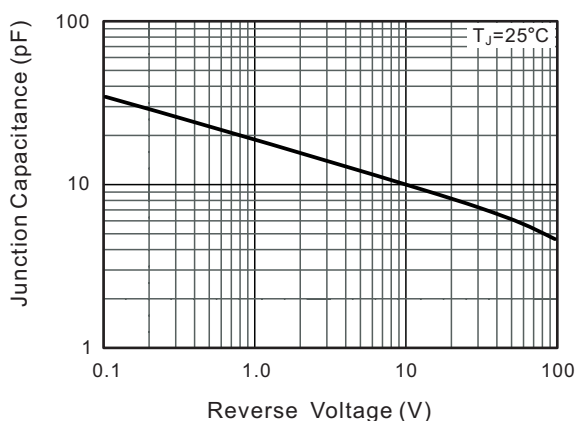
**Fig.2 Typical Reverse Characteristics**



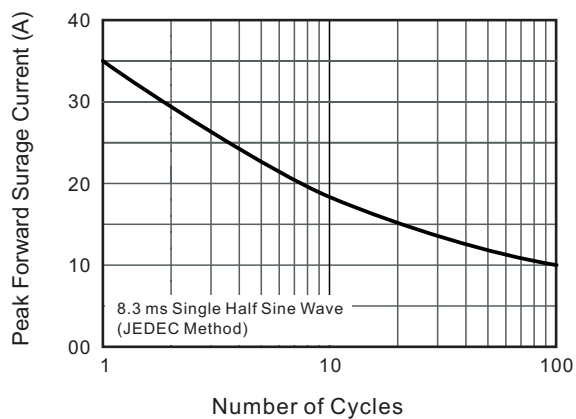
**Fig.3 Typical Instaneous Forward Characteristics**



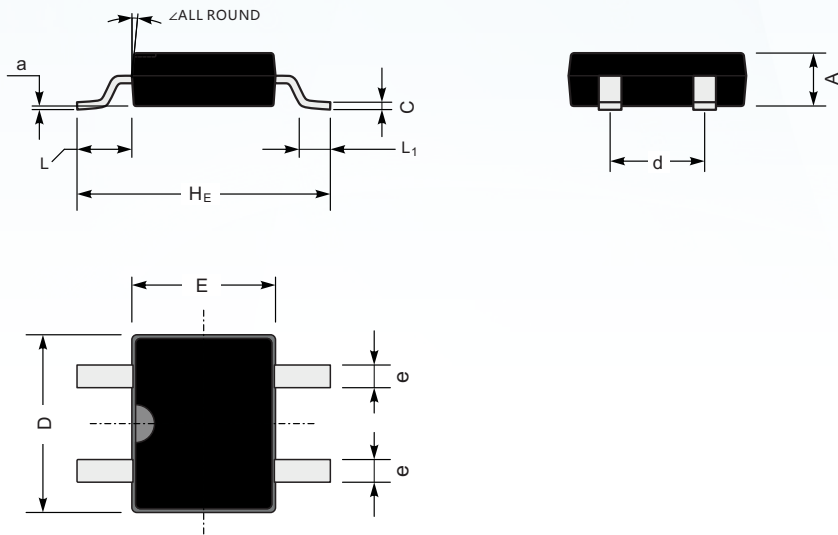
**Fig.4 Typical Junction Capacitance**



**Fig.5 Maximum Non-Repetitive Peak Forward Surge Current**



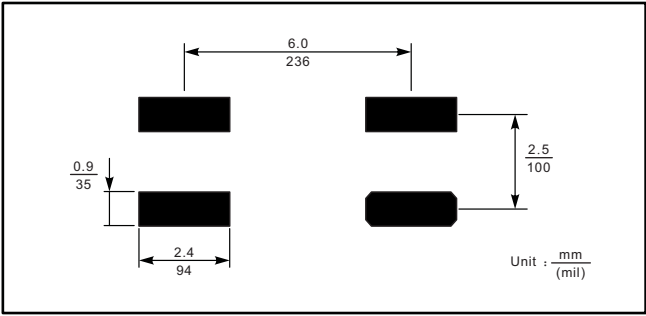
■ ABS



MBF mechanical data

UNIT		A	C	D	E	H <sub>E</sub>	d	e	L	L <sub>1</sub>	a	∠
mm	max	1.6	0.22	5.0	4.1	7.0	2.7	0.8	1.7	1.1	0.2	7°
	min	1.2	0.15	4.5	3.6	6.4	2.3	0.5	1.3	0.5	—	
mil	max	63	8.7	197	161	276	106	31	67	43	8	
	min	47	5.9	177	142	252	91	20	51	20	—	

The recommended mounting pad size



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